

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	24	"6351410".pn. "6163477".pn. US-6341053-\$.DID. OR US-6418048-\$.DID. OR US-6456525-\$.DID. OR US-6542341-\$.DID. OR US-6282069-\$.DID. OR US-6700760-\$.DID. OR US-5640343-\$.DID. OR US-6655006-\$.DID. "20020154455" "6689622".pn.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 10:53
L3	71	(free near layer) near3 (oe or oersted)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 11:01
L4	859	(free or sense) near5 (pinning or biasing or bias or antiferromagnetic or afm or anti-ferromagnetic or biased or offset) and (pinned or fixed) and (mram or word near line or bit near line or digit near line or wordline or bitline or digitline)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 11:03
L6	4	("5650958" "6114719" "6134139" "6166948").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/12/10 11:36
L7	281	(free or sense) near3 (pinning or biasing or bias or antiferromagnetic or afm or anti-ferromagnetic) and (pinned or fixed) and (word near line or bit near line or digit near line or wordline or bitline or digitline)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 11:54
L8	115	(magnetoresistance or magnetoresistive or tnr or mtj or gmr) and (mram or bit near line or word near line or digit near line or bitline or wordline or digitline or feram or magnetic near memory) and (free or sense or storage or recording) near3 (afm or antiferromagnetic or anti-ferromagnetic)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 12:51
L9	10	("6341053").URPN.	USPAT	OR	ON	2004/12/10 12:45
L10	188	(magnetoresistance or magnetoresistive or tnr or mtj or gmr) and (mram or bit near line or word near line or digit near line or bitline or wordline or digitline or feram or magnetic near memory) and (free or sense or storage or recording) near3 (offset or hysteresis or switching near field or offsetting or small near bias)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 13:42
L11	39	(magnetoresistance or magnetoresistive or tnr or mtj or gmr) and (afm or antiferromagnetic or anti-ferromagnetic) near2 (abutting or abut or touching or adjacent or overlying or underlying or above or below or on or over) near2 (free or sense or storage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 13:56
L12	9	(magnetoresistance or magnetoresistive or tnr or mtj or gmr) and (afm or antiferromagnetic or anti-ferromagnetic) near2 (stabiliz\$5) near2 (free or sense or storage)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/10 13:57